

# EVVOSEMI<sup>®</sup>

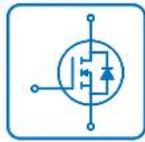
THINK CHANGE DO



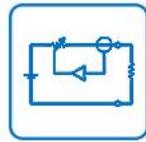
ESD



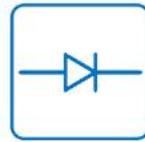
TVS



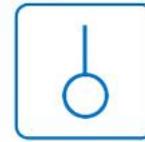
MOS



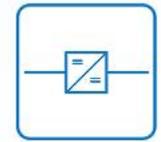
LDO



Diode



Sensor



DC-DC

## Product Specification

▶ Domestic	Part Number	GBJ/KBJ35005 THRU GBJ/KBJ3510
▶ Overseas	Part Number	GBJ/KBJ35005 THRU GBJ/KBJ3510
▶ Equivalent	Part Number	GBJ/KBJ35005 THRU GBJ/KBJ3510

EV is the abbreviation of name EVVO

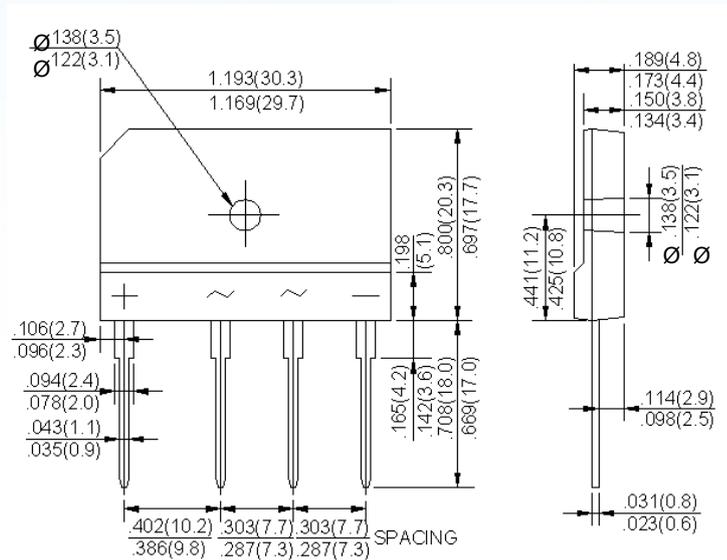
**GLASS PASSIVATED  
BRIDGE RECTIFIERS**

REVERSE VOLTAGE - **50 to 1000**Volts  
FORWARD CURRENT - **35** Amperes

**FEATURES**

- Rating to 1000V PRV
- Ideal for printed circuit board
- Low forward voltage drop, high current capability
- Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- The plastic material has UL flammability classification 94V-0

**GBJ**



Dimensions in inches and (millimeters)

**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave ,60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	GBJ/KBJ 35005	GBJ/KBJ 3501	GBJ/KBJ 3502	GBJ/KBJ 3504	GBJ/KBJ 3506	GBJ/KBJ 3508	GBJ/KBJ 3510	UNIT
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V <sub>RMS</sub>	30	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current (with heatsink Note 2) @ T <sub>c</sub> =100°C (without heatsink)	I <sub>(AV)</sub>	35.0 5.0							A
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load (JEDEC Method)	I <sub>FSM</sub>	360							A
Maximum Forward Voltage at 17.5A DC	V <sub>F</sub>	1.1							V
Maximum DC Reverse Current at Rated DC Blocking Voltage @ T <sub>J</sub> =25°C @ T <sub>J</sub> =125°C	I <sub>R</sub>	10 500							uA
I <sup>2</sup> t Rating for Fusing (t<8.3ms)	I <sup>2</sup> t	510							A <sup>2</sup> s
Typical Junction Capacitance Per Element (Note1)	C <sub>J</sub>	85							pF
Typical Thermal Resistance (Note2)	R <sub>θJC</sub>	0.6							°C/W
Operating Temperature Range	T <sub>J</sub>	-55to+150							°C
Storage Temperature Range	T <sub>STG</sub>	-55to+150							°C

NOTES: 1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.  
2.Device mounted on 300mm\*300mm\*1.6mm cu plate heatsink.

## Disclaimer

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